



2811 IFW

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On: June 4, 2004

By: Richard D. Fuerle

Signature: 

Date: June 4, 2004

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: YOSHIYUKI ANDO

Examiner: Loke, Steven Ho Yin

Serial No.: 10/065,955

Group Art Unit: 2811

Filed: December 04, 2002

For: ION IMPLANTATION METHODS AND TRANSISTOR
CELL LAYOUT FOR FIN TYPE TRANSISTORS

The Commissioner of Patents
and Trademarks
Washington, D.C. 20231

AMENDMENT

In response to the Office Action dated May 18, 2004 please amend the above-identified patent application as follows: